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To cite this version:

HAL Id: hal-00581868
https://hal.science/hal-00581868
Submitted on 1 Apr 2011
Improving the contact resistance at low force using gold coated carbon nanotube surfaces.

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Abstract. Investigations to determine the electrical contact performance under repeated cycles at low force conditions for carbon-nanotube (CNT) coated surfaces were performed. The surfaces under investigation consisted of multi-walled CNT synthesized on a silicon substrate and coated with a gold film. These planar surfaces were mounted on the tip of a PZT actuator and contacted with a plated Au hemispherical probe. The dynamic applied force used was 1mN. The contact resistance ($R_c$) of these surfaces was investigated with the applied force and with repeated loading cycles performed for stability testing. The surfaces were compared with a reference Au-Au contact under the same experimental conditions. This initial study shows the potential for the application of gold coated CNT surfaces as an interface in low force electrical contact applications.

PACS. Contact force, contact resistance, carbon nanotubes, and Au/multi walled carbon nanotubes.

1 Introduction

This paper presents a study of electrical contact between surfaces under low dynamic force conditions, typically 1mN. Such conditions are relevant to a number of micro-contact applications, for example MEMS relay devices. There are a number of potential materials commonly used for this application including gold, palladium and platinum [1]. The weakness of such materials is that they are relatively soft and wear easily. Other materials which are of interest on MEMS relay’s micro-contact include silicon carbide and diamond films. Both have high moduli but low electrical conductivity. The latter makes them unsuitable for electrical contact applications. There have been attempts to increase the conductivity. When doping SiC film with NH3 the resistivity drops to $1 \times 10^{-5}$ $\Omega$ m [2] and doping DLC with ruthenium the resistivity drops to $1 \times 10^{5}$ $\Omega$ m [3], however, both materials still have a high resistivity compared to gold and even gold alloys (for example Au-6.3% Pt has a resistivity of $7.17 \times 10^{-5}$ $\Omega$ m) [1].

A carbon nanotube (CNT) coated surface has potential as a material for MEMS relay applications specifically as a contact material because of its excellent mechanical and electrical properties. An experiment has been performed [4] to measure the contact resistance, $R_c$ between CNT coated electrodes in ambient air and in a vacuum. The author concluded that the contact resistance, $R_c$ was found to be much lower in ambient air (~160 $\Omega$) than in vacuum (>4k$\Omega$). In a more recent experiment [5], Au contacts with a substrate coated with tangled single walled carbon nanotubes were investigated. The authors concluded that a tangled Single Walled Carbon Nanotube (SWCNT) film against an Au coated surface has a better performance than two contacting tangled films. The following mechanical properties have been determined; CNTs tensile strength of up to 63 GPa has been measured [6]. Experiments using an atomic force microscope were performed to measure the elastic modulus and bending strength of individual, structurally isolated, multi-wall carbon nanotubes and indicated values of 1.26 TPa and 14.2 GPa [7] respectively. Experiments were also conducted on CNTs using a nano-indentation apparatus and values were obtained for the bending modulus; 1.24 TPa, axial modulus; 1.23 TPa and wall modulus; 5.61 TPa [8]. Another report shows that CNT’s have an elastic modulus greater than 1 TPa [9] compared to diamond, which has a modulus of 1.2 TPa.

In terms of its electrical properties, it is calculated that a 4-10 $\mu$m long SWCNT with a diameter of 1.2nm has a resistivity of $0.88 \times 10^{-5}$ $\Omega$ m and is thought to exhibit ballistic electrical conduction. The calculation is performed using the theory of ballistic conductors and it is assumed that the CNT is defect-free. In addition, if a CNT were to be filled with metal, to form a composite its resistivity would fall to $0.35 \times 10^{-5}$ $\Omega$ m [10]. The mechanical and electrical properties are therefore potentially comparable to diamond and gold respectively, however, as yet no experiments have been reported on CNT metal composites for micro-contact applications. In the present work a novel approach is used in which a CNT “forest” is over coated with gold, in order to provide a high conductivity surface layer with a compliant under layer.

In previous work a modified nano-indentation apparatus [11] was used to determine the contact resistance, $R_c$, as a function of contact force and load cycling up to ten load cycles. These initial results showed that the performance and contact resistance of Au-Au/MWCNT contact pairs is comparable to Au-Au contact pairs and during ten load cycles of Au-Au/MWNT contact pairs shows stable contact resistance. The contact resistance of the Au-Au/MWCNT is typically 0.5$\Omega$ at 1mN. This compares
favorably with commercial MEMS relays where $1.5\Omega$ is a common contact resistance. In this study a purpose built test system is used to investigate the dynamic performance of the surfaces under dry circuit conditions.

2 Material preparation

In the present study two contact pairs have been investigated; Au to Au and Au to Au/multi walled carbon nano-tubes (MWCNTs) composite. The geometry selected is a 2mm diameter hemisphere contacting a flat surface. In all cases the hemisphere consists of a stainless steel base, sputter coated with Au, ~500 nm thick, with surface roughness $R_a=400\text{nm}$. In the Au to Au case (Sample 1), the flat surface is a silicon (Si) substrate (~2mm by 7mm), sputter coated with Au ~500 nm, with a surface roughness $R_a=30\text{nm}$.

For the Au to Au/MWCNT case (Sample 2), a “forest” of MWCNTs is grown on the Si wafer using thermal CVD. The catalyst used is sputter deposited Fe and the gaseous carbon source is ethylene. The growth temperature and time is 875°C and 3 minutes respectively to produce a dense forest of vertically aligned MWCNT of an average length of ~50µm as shown in Fig 1. Au is then sputtered on the upper surface of the MWCNT forest to produce Au/MWCNT composite coatings as shown in Fig 2. It is shown in Fig 3, that the Au penetrates the MWCNT surface to a depth of ~4 µm.

3 Experimental

In order to determine the performance of the surfaces under repeated switching actions, an apparatus has been designed, in which a PZT actuator is used to support the planar coated surfaces as shown in Fig 4. This surface makes electrical contact with the hemispherical Au-coated probe to mimic the actuation of a MEMS relay micro-contact. The apparatus has been designed to allow control of the gap and to allow the performance of the contact materials to be investigated ultimately over large numbers of switching cycles (>10⁶).
A signal generator with voltage amplification is used to actuate the PZT actuator as shown in Fig 5. The PZT actuator's layers consist of Nickel (1st layer), PZT material (Lead Zirconate Titanate) (2nd layer), Nickel (3rd layer) and Kovar (Nickel-Cobalt ferrous alloy, final layer). The resonance frequency of the PZT actuator is ~900Hz (1st harmonic). In this experiment the PZT actuator is actuated at low frequency 0.2Hz to allow a quasi-static study of the contact surfaces. The dynamic force is measured using a piezoelectric force sensor [12-15] situated as shown in Figs 4 and 5. The force sensor is amplified using a charge amplifier and the dynamic force monitored.

There are several methods to control the applied force as follows; 1) By controlling the gap [16]. This can be achieved by turning the adjustment screw as shown in Fig 4 and the contact gap is monitored using a triangular laser, 2) By controlling the length of the actuator [14], and 3) By controlling the amplitude of the supply voltage to the actuator. In the experiment presented here all other parameters are held constant, with the contact gap used to set the contact force at 1mN.

The contact resistance, $R_c$ is measured using the 4 wire-measurement methods as shown in Fig 5 and 6. The DC current source across the planar coated surfaces and micro-contact is set at 1mA using a Keithley 580 micro-ohmmeter. The number of cycles and contact resistance can be controlled and extracted by using the control and data acquisition program. The apparatus is enclosed and held at ambient air and room temperature.

In this experiment, the PZT actuator is actuated up to 1000 cycles at 0.2 Hz under dry circuit conditions (maximum supply of 20mV at 1mA) with the contact resistance $R_c$ measured simultaneously. The aim of this initial study is to determine the stability of the contact surfaces, prior to longer duration testing at higher frequencies, an applied force of 1mN is used for consistency with previous results using a nano-indenter, [11]. The coated planar surface and
Au balls are brought into contact at 0.2 Hz using an applied square wave form, and the gap and amplitude adjusted so that a maximum load of 1 mN is reached. The targeted load is applied for ~3 seconds so that a representative average contact resistance value can be determined. Fig 7 shows an example of the load history over a period of time.

The performance of the Au-Au/MWCNT surfaces is compared to a reference Au-Au contact pair under the same experimental conditions in order to assess their mechanical and electrical stability. A TaiCaan Technologies XYRIS 4000CL laser scanner is used to confirm any changes on the contact surfaces samples such as degradation and wear.

4 Results and discussion

Fig 8 shows the contact resistance of Au-Au and Au-Au/MWCNT pairs over 1000 load cycles at a maximum (quasi static) applied load of 1 mN. The contact resistance of the Au-Au pair is initially ~0.2 Ω and increases rapidly to 4-6 Ω at 450 cycles. Under dry circuit conditions the contacts are unlikely to degrade by “hot-switching”, therefore the increase in contact resistance is solely due to the mechanical deterioration of the Au-Au contact pair surfaces, reflecting the recognized problems of using soft metals for electrical contacts on a hard substrate. The reason for the sharp increase in $R_c$ of Au-Au pair at ~430 cycles is believed to be due to the initial smoothing of the Au surfaces which leads to increased adhesion [17]. The smoothing is the result of the repeated impacts and time-dependent deformation of the Au. Fig 9 which shows the damaged Au surface planar for the Au-Au contact pair.

The adhesive force increases with the number of cycles and is consistent with creep being one of the underlying physical mechanisms for the increase in adhesion [18]. The creep of the gold was shown in [11] during a single load cycle, as shown in Fig 10. Fig 10 shows the graph of load against displacement for an Au-Au contact pair. The experiment was carried out by replacing the diamond tip indenter with the Au hemispherical probe of a nano-indentation apparatus. The curve shows there is creep, a deformation that occurs over a period of time when a material is subjected to constant stress, even at room temperature. The force cycle exhibited in Fig 11 occurs over a longer holding time scale than that used in the test procedure.

The stable contact resistance data between 1-400 cycles in Fig 8, shows the Au-Au interface is ~0.2 Ω, while the Au-Au/MWCNT interface is ~0.5 Ω. If we assume the standard Holm electrical contact model (1) and (2), then it is apparent that the main difficulty in comparing the two surfaces is in the determination of the conductivity. On first inspection if we assume the conductivity is the same in both cases then the contact area in the Au-Au/MWCNT interface would be smaller, this is assumed to not the case. Firstly the conductivity of the Au-Au/MWCNT interface is expected to be a function of the CNT surface structure and the Au surface; this has yet to be defined. Secondly it has
been suggested that the standard Holm model does not apply to thin film surfaces, [11].

\[ R_c \approx \frac{\rho}{2\alpha} \]  
\[ A_c = \pi\alpha^2 \]  (1)  (2)

Fig. 10. Graph of load against displacement for Au-Au contact pair.

Fig 8 also shows contact resistance of Au-Au/MWCNT contact pair. The initial contact resistance (~0.7\( \Omega \)) is higher for the Au-Au/MWNT pair. The likely cause is the difference of surface roughness between Au and Au/MWCNT coated planar surface and the irregularity of the Au film on the MWCNT. It is anticipated that this can be improved in subsequent experiments by better process control. The contact resistance is much more stable than for the Au-Au pair over the 1000 loading cycles. This is believed to be due to the Au/MWCNT surfaces conforming to the shape of the Au hemispherical probe. The dynamic impact on the Au hemispherical probe is absorbed by the Au/MWCNT surfaces thus reducing the wear. The sponge-like effect on Au-Au/MWCNT helps to reduce the deterioration. Furthermore, as the applied load is increased, more deflection occurs of the MWNTs closing the air gaps between the vertically aligned MWNTs thus improving the transfer of electrons [11].

Fig 11 shows a graph of load against displacement using a modified nanoindentation apparatus with Au-Au, and Au-Au/MWCNT contact pair. It shows the depth of penetration during the impact. The curve for Au-Au/MWCNT pair shows that there is much depth penetration compared with Au-Au pair (~70 nm and ~2500nm respectively). Once the indentation load is removed permanent displacement can be observed (~1400 nm). In [11] the results show an SEM image of the Au hemispherical probe contact surface after the load cycles having some damage to the Au surfaces where many small impressions on the Au hemispherical probe are detected. These impressions are due to the asperities on the MWNT surfaces. Moreover when the surface roughness (\( R_s \)) is measured in this region it has changed from ~400 nm to ~1.5\( \mu m \).

In addition, as the Au/MWNTs surface conforms to the shape of the Au hemispherical probe it increases the contact area. There is a smoothening of the Au asperity and a significant indentation marks on the Au covering the surface of the Au hemispherical probe as shown in ‘A’ and ‘B’ respectively on Fig 12. An SEM investigation has shown there to be no damage on the Au/MWCNT planar composite, further suggesting that the CNT under layer has improved the mechanical integrity of the gold surface.
5 Conclusion

The applied cyclic load and contact resistance between Au-Au/MWCNT composite contact pairs was investigated using a PZT actuator apparatus and $R_c$ measurement methods. This contact pair combination was compared with an Au-Au contact pair. Over 1000 load cycles the Au-Au/MWCNT contact pair demonstrated a much more stable contact resistance than Au-Au contact pair. This improvement is believed to be due to Au/MWCNT surface conforming readily with the dynamic impact of the Au hemispherical probe thus decreasing the tendency of smoothing and adhesion that damages the surfaces.

Acknowledgments

The authors thank Dr. David Smith of the School of Physics and Astronomy, for providing the facilities for developing the MWCNT deposition, and to Mr. Tim Hartley for his dedication in designing and fabricating the test apparatus.

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